# Quad Differential Input, Low Power Operational Amplifiers

The LM324 series are low-cost, quad operational amplifiers with true differential inputs. They have several distinct advantages over standard operational amplifier types in single supply applications. The quad amplifier can operate at supply voltages as low as 3.0 V or as high as 32 V with quiescent currents about one-fifth of those associated with the MC1741 (on a per amplifier basis). The common mode input range includes the negative supply, thereby eliminating the necessity for external biasing components in many applications. The output voltage range also includes the negative power supply voltage.

- Short Circuited Protected Outputs
- True Differential Input Stage
- Single Supply Operation: 3.0 V to 32 V (LM224, LM324, LM324A)
- Low Input Bias Currents: 100 nA Maximum (LM324A)
- Four Amplifiers Per Package
- Internally Compensated
- Common Mode Range Extends to Negative Supply
- Industry Standard Pinouts
- ESD Clamps on the Inputs Increase Ruggedness without Affecting Device Operation

# **MAXIMUM RATINGS** ( $T_A = +25^{\circ}C$ , unless otherwise noted.)

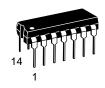
Rating	Symbol	LM224 LM324, LM324A	LM2902, LM2902V	Unit		
Power Supply Voltages Single Supply Split Supplies	V <sub>CC</sub>	32 ±16	26 ±13	Vdc		
Input Differential Voltage Range (Note 1.)	V <sub>IDR</sub>	±32	±26	Vdc		
Input Common Mode Voltage Range	V <sub>ICR</sub>	-0.3 to 32	-0.3 to 26	Vdc		
Output Short Circuit Duration	t <sub>SC</sub>	Contin	nuous			
Junction Temperature	TJ	15	150			
Storage Temperature Range	T <sub>stg</sub>	–65 to	-65 to +150			
Operating Ambient Temperature Range	T <sub>A</sub>			°C		
LM224		-25 to +85				
LM324, 324A		0 to +70				
LM2902			-40 to +105			
LM2902V			-40 to +125			

<sup>1.</sup> Split Power Supplies.



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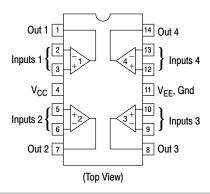


PDIP-14 N SUFFIX CASE 646



SO-14 D SUFFIX CASE 751A

#### **PIN CONNECTIONS**



#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 9 of this data sheet.

#### **DEVICE MARKING INFORMATION**

See general marking information in the device marking section on page 10 of this data sheet.

## **ELECTRICAL CHARACTERISTICS** ( $V_{CC} = 5.0 \text{ V}$ , $V_{FF} = \text{Gnd}$ , $T_A = 25^{\circ}\text{C}$ , unless otherwise noted.)

			LM224			LM324	4		LM324	!		LM290	2		LM2902	2V	
Characteristics	Symbol	Min	Тур	Max	Unit												
Input Offset Voltage $\begin{split} &V_{CC}=5.0 \text{ V to } 30 \text{ V} \\ &(26 \text{ V for LM2902, V)}, \\ &V_{ICR}=0 \text{ V to} \\ &V_{CC}-1.7 \text{ V}, \\ &V_{O}=1.4 \text{ V}, R_{S}=0  \Omega \end{split}$ $&T_{A}=25^{\circ}\text{C}$ $&T_{A}=T_{high} \text{ (Note 2.)}$	V <sub>IO</sub>		2.0	5.0 7.0		2.0	3.0 5.0		2.0	7.0 9.0		2.0	7.0 10		2.0	7.0 13	mV
$T_A = T_{low}$ (Note 2.)		_	_	7.0	_		5.0	-	-	9.0	_	-	10	_	_	10	
Average Temperature Coefficient of Input Offset Voltage $T_A = T_{high}$ to $T_{low}$ (Notes 2. and 4.)	ΔV <sub>IO</sub> /ΔΤ	_	7.0	-	-	7.0	30	-	7.0	_	_	7.0	_	-	7.0	_	μV/°C
Input Offset Current $T_A = T_{high}$ to $T_{low}$ (Note 2.)	I <sub>IO</sub>	-	3.0	30 100	-	5.0	30 75	-	5.0	50 150	-	5.0 _	50 200	-	5.0	50 200	nA
Average Temperature Coefficient of Input Offset Current $T_A = T_{high}$ to $T_{low}$ (Notes 2. and 4.)	ΔΙ <sub>ΙΟ</sub> /ΔΤ	-	10	-	-	10	300	-	10	-	-	10	-	-	10	-	pA/°C
Input Bias Current $T_{A} = T_{high} \text{ to } T_{low}$ (Note 2.)	I <sub>IB</sub>	-	-90 -	-150 -300	- -	-45 -	-100 -200	-	-90 -	-250 -500	- -	-90 -	-250 -500	-	-90 -	-250 -500	nA
Input Common Mode Voltage Range (Note 3.) V <sub>CC</sub> = 30 V (26 V for LM2902, V)	V <sub>ICR</sub>	0	_	28.3	0	_	28.3	0	_	28.3	0	-	24.3	0	_	24.3	V
$V_{CC} = 30 \text{ V}$ (26 V for LM2902, V), $T_A = T_{high}$ to $T_{low}$ (Note 2.)		0	_	28	0	_	28	0	-	28	0	-	24	0	-	24	
Differential Input Voltage Range	V <sub>IDR</sub>	-	-	V <sub>CC</sub>	-	-	V <sub>CC</sub>	-	-	V <sub>CC</sub>	_	-	V <sub>CC</sub>	-	-	V <sub>CC</sub>	V
Large Signal Open Loop Voltage Gain $R_L = 2.0 \text{ k}\Omega$ , $V_{CC} = 15 \text{ V}$ , for Large $V_O$ Swing $T_A = T_{high}$ to $T_{low}$ (Note 2.)	Avol	50 25	100		25 15	100	-	V/mV									
Channel Separation 10 kHz $\leq$ f $\leq$ 20 kHz, Input Referenced	CS	-	-120	-	-	-120	_	-	-120	-	-	-120	-	-	-120	-	dB
Common Mode Rejection, $R_S \leq 10 \; k\Omega$	CMR	70	85	-	65	70	-	65	70	-	50	70	-	50	70	-	dB
Power Supply Rejection	PSR	65	100	-	65	100	-	65	100	_	50	100	_	50	100	_	dB

2. LM224: T<sub>low</sub> = -25°C, T<sub>high</sub> = +85°C
LM324/LM324A: T<sub>low</sub> = 0°C, T<sub>high</sub> = +70°C
LM2902: T<sub>low</sub> = -40°C, T<sub>high</sub> = +105°C
LM2902V: T<sub>low</sub> = -40°C, T<sub>high</sub> = +125°C
3. The input common mode voltage or either input signal voltage should not be allowed to go negative by more than 0.3 V. The upper end of

4. Guaranteed by design.

the common mode voltage range is  $V_{CC}$  –1.7 V.

 $\textbf{ELECTRICAL CHARACTERISTICS} \ \ (\text{V}_{CC} = 5.0 \text{ V}, \text{ V}_{EE} = \text{Gnd}, \text{ T}_{A} = 25^{\circ}\text{C}, \text{ unless otherwise noted.})$ 

			LM224		., .	LM324	A	LM324		LM2902			LM2902V				
Characteristics	Symbol	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
Output Voltage— High Limit (T <sub>A</sub> = T <sub>high to</sub> T <sub>low</sub> ) (Note 5.)	V <sub>OH</sub>																V
$V_{CC} = 5.0 \text{ V}, R_{L} = 2.0 \text{ k}\Omega, T_{A} = 25^{\circ}\text{C}$		3.3	3.5	_	3.3	3.5	-	3.3	3.5	_	3.3	3.5	_	3.3	3.5	_	
$V_{CC} = 30 \text{ V}$ (26 V for LM2902, V), $R_L = 2.0 \text{ k}\Omega$		26	-	-	26	-	-	26	-	-	22	-	-	22	-	-	
$V_{CC} = 30 \text{ V}$ (26 V for LM2902, V), $R_L = 10 \text{ k}\Omega$		27	28	ı	27	28	ı	27	28	_	23	24	-	23	24	-	
$\label{eq:continuity} \begin{split} & \text{Output Voltage} - \\ & \text{Low Limit,} \\ & \text{V}_{CC} = 5.0 \text{ V,} \\ & \text{R}_L = 10 \text{ k}\Omega, \\ & \text{T}_A = \text{T}_{high} \text{ to T}_{low} \\ & \text{(Note 5.)} \end{split}$	V <sub>OL</sub>	_	5.0	20	-	5.0	20	-	5.0	20	-	5.0	100	_	5.0	100	mV
Output Source Current (V <sub>ID</sub> = +1.0 V, V <sub>CC</sub> = 15 V)	I <sub>O +</sub>	20	40	ı	20	40	ı	20	40		20	40		20	40	_	mA
$T_{A} = 25^{\circ}C$ $T_{A} = T_{high} \text{ to } T_{low}$ (Note 5.)		10	20	-	10	20	_	10	20	_	10	20	_	10	20	-	
Output Sink Current $(V_{ID} = -1.0 \text{ V},$ $V_{CC} = 15 \text{ V})$ $T_A = 25^{\circ}\text{C}$	I <sub>O</sub> _	10	20	-	10	20	-	10	20	_	10	20	_	10	20	-	mA
$T_A = T_{high}$ to $T_{low}$ (Note 5.)		5.0	8.0	-	5.0	8.0	-	5.0	8.0	-	5.0	8.0	-	5.0	8.0	_	
$(V_{ID} = -1.0 \text{ V},$ $V_{O} = 200 \text{ mV},$ $T_{A} = 25^{\circ}\text{C})$		12	50	-	12	50	-	12	50	-	_	-	-	_	-	_	μΑ
Output Short Circuit to Ground (Note 6.)	I <sub>SC</sub>	-	40	60	-	40	60	ı	40	60	-	40	60	-	40	60	mA
Power Supply Current $(T_A = T_{high} \text{ to } T_{low})$ $(\text{Note 5.})$ $V_{CC} = 30 \text{ V}$ $(26 \text{ V for LM2902, V)},$	I <sub>CC</sub>	_	1	3.0	_	1.4	3.0	_	-	3.0	_	-	3.0	-	-	3.0	mA
$V_{O} = 0 \text{ V}, R_{L} = \infty$ $V_{CC} = 5.0 \text{ V}, R_{L} = \infty$		-	ı	1.2	-	0.7	1.2	-	-	1.2	-	-	1.2	_	-	1.2	

5. LM224: T<sub>low</sub> = -25°C, T<sub>high</sub> = +85°C

LM324/LM324A: T<sub>low</sub> = 0°C, T<sub>high</sub> = +70°C

LM2902: T<sub>low</sub> = -40°C, T<sub>high</sub> = +105°C

LM2902V: T<sub>low</sub> = -40°C, T<sub>high</sub> = +125°C

6. The input common mode voltage or either input signal voltage should not be allowed to go negative by more than 0.3 V. The upper end of

the common mode voltage range is  $V_{\mbox{\footnotesize{CC}}}$  –1.7 V.

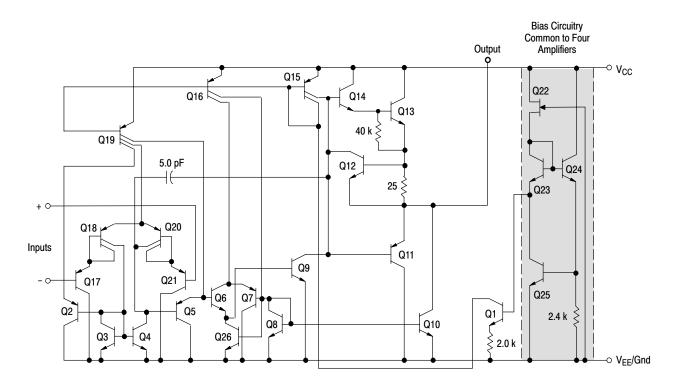


Figure 1. Representative Circuit Diagram (One–Fourth of Circuit Shown)

#### **CIRCUIT DESCRIPTION**

The LM324 series is made using four internally compensated, two-stage operational amplifiers. The first stage of each consists of differential input devices Q20 and Q18 with input buffer transistors Q21 and Q17 and the differential to single ended converter Q3 and Q4. The first stage performs not only the first stage gain function but also performs the level shifting and transconductance reduction functions. By reducing the transconductance, a smaller compensation capacitor (only 5.0 pF) can be employed, thus saving chip area. The transconductance reduction is accomplished by splitting the collectors of Q20 and Q18. Another feature of this input stage is that the input common mode range can include the negative supply or ground, in single supply operation, without saturating either the input devices or the differential to single-ended converter. The second stage consists of a standard current source load amplifier stage.

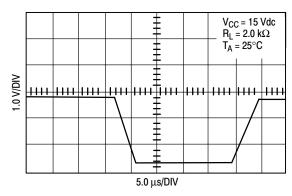
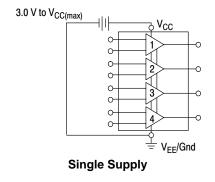


Figure 2. Large Signal Voltage Follower Response

Each amplifier is biased from an internal-voltage regulator which has a low temperature coefficient thus giving each amplifier good temperature characteristics as well as excellent power supply rejection.



V<sub>CC</sub> (max)

1.5 V to V<sub>CC(max)</sub>

1.5 V to V<sub>EE(max)</sub>

Split Supplies

Figure 3.

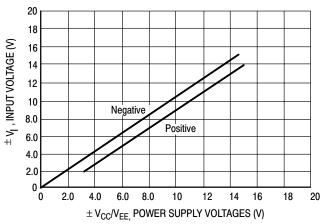


Figure 4. Input Voltage Range

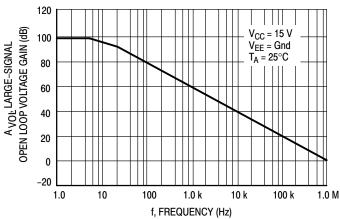


Figure 5. Open Loop Frequency

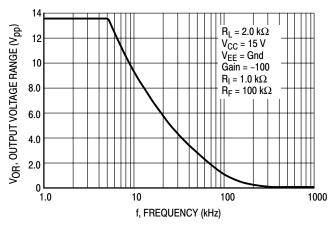


Figure 6. Large-Signal Frequency Response

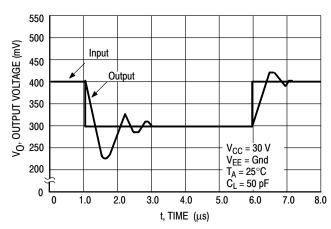


Figure 7. Small–Signal Voltage Follower Pulse Response (Noninverting)

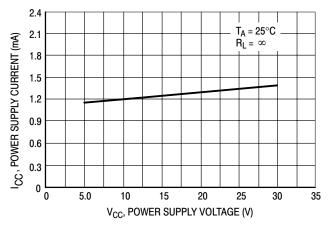


Figure 8. Power Supply Current versus Power Supply Voltage

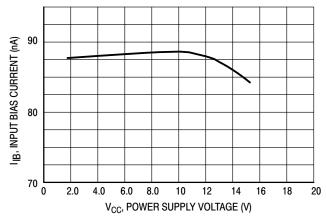


Figure 9. Input Bias Current versus Power Supply Voltage

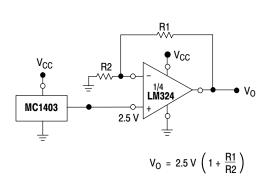


Figure 10. Voltage Reference

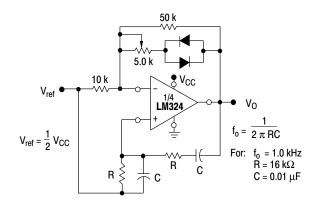


Figure 11. Wien Bridge Oscillator

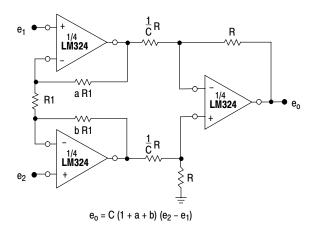


Figure 12. High Impedance Differential Amplifier

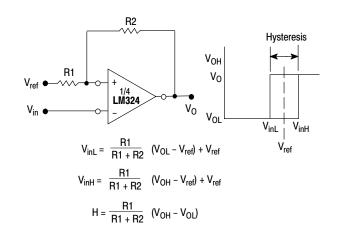


Figure 13. Comparator with Hysteresis

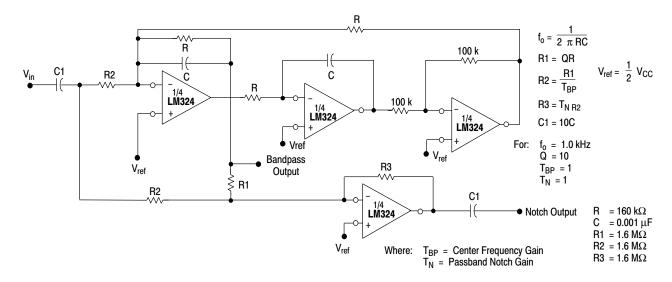


Figure 14. Bi-Quad Filter

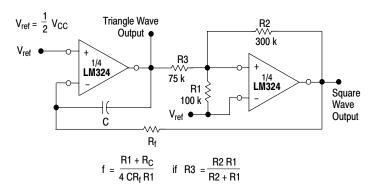


Figure 15. Function Generator

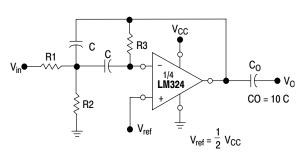


Figure 16. Multiple Feedback Bandpass Filter

Given:  $f_0$  = center frequency

A(f<sub>o</sub>) = gain at center frequency

Choose value fo, C

Then: R3 = 
$$\frac{Q}{\pi f_0 C}$$

$$R2 = \frac{R1 R3}{4Q^2 R1 - R3}$$

For less than 10% error from operational amplifier,  $\frac{Q_0 \, f_0}{BW} \, < 0.1$ 

where fo and BW are expressed in Hz.

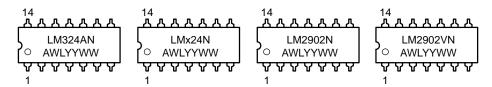
If source impedance varies, filter may be preceded with voltage follower buffer to stabilize filter parameters.

# **ORDERING INFORMATION**

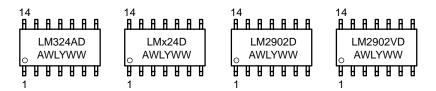
Device	Package	Operating Temperature Range	Shipping
LM224D	SO-14		55 Units/Rail
LM224DR2	SO-14	−25° to +85°C	2500 Tape & Reel
LM224N	PDIP-14	7	25 Units/Rail
LM324D	SO-14		55 Units/Rail
LM324DR2	SO-14		2500 Tape & Reel
LM324N	PDIP-14	00 45 . 7000	25 Units/Rail
LM324AD	SO-14	0° to +70°C	55 Units/Rail
LM324ADR2	SO-14		2500 Tape & Reel
LM324AN	PDIP-14	7	25 Units/Rail
LM2902D	SO-14		55 Units/Rail
LM2902DR2	SO-14	-40° to +105°C	2500 Tape & Reel
LM2902N	PDIP-14	7	25 Units/Rail
LM2902VD	SO-14		55 Units/Rail
LM2902VDR2	SO-14	-40° to +125°C	2500 Tape & Reel
LM2902VN	PDIP-14	7	25 Units/Rail

## **MARKING DIAGRAMS**

PDIP-14 N SUFFIX CASE 646



SO-14 D SUFFIX CASE 751A



x = 2 or 3

A = Assembly Location

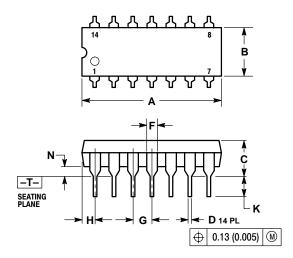
WL = Wafer Lot

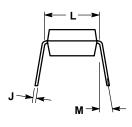
YY, Y = Year

WW = Work Week

## **PACKAGE DIMENSIONS**

### PDIP-14 **N SUFFIX** CASE 646-06 ISSUE M





- NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

- Y 14.5M, 1982.

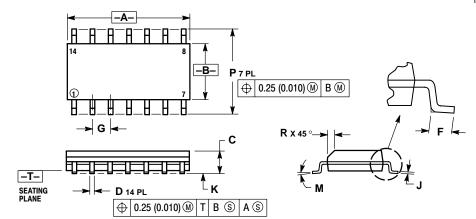
  CONTROLLING DIMENSION: INCH.

  DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.

  DIMENSION B DOES NOT INCLUDE MOLD FLASH.
- 5. ROUNDED CORNERS OPTIONAL.

	INC	HES	MILLIMETERS					
DIM	MIN	MAX	MIN	MAX				
Α	0.715	0.770	18.16	18.80				
В	0.240	0.260	6.10	6.60				
С	0.145	0.185	3.69	4.69				
D	0.015	0.021	0.38	0.53				
F	0.040	0.070	1.02	1.78				
G	0.100	BSC	2.54 BSC					
Н	0.052	0.095	1.32	2.41				
7	0.008	0.015	0.20	0.38				
K	0.115	0.135	2.92	3.43				
L	0.290	0.310	7.37	7.87				
M		10°		10°				
N	0.015	0.039	0.38	1.01				

### SO-14 **D SUFFIX** CASE 751A-03 ISSUE F



#### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.
  3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
- 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
- PER SIDE.

  5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	IETERS	INCHES					
DIM	MIN	MAX	MIN	MAX				
Α	8.55	8.75	0.337	0.344				
В	3.80	4.00	0.150	0.157				
С	1.35	1.75	0.054	0.068				
D	0.35	0.49	0.014	0.019				
F	0.40	1.25	0.016	0.049				
G	1.27	BSC	0.050 BSC					
J	0.19	0.25	0.008	0.009				
K	0.10	0.25	0.004	0.009				
M	0 °	7°	0 °	7°				
Р	5.80	6.20	0.228	0.244				
R	0.25	0.50	0.010	0.019				

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